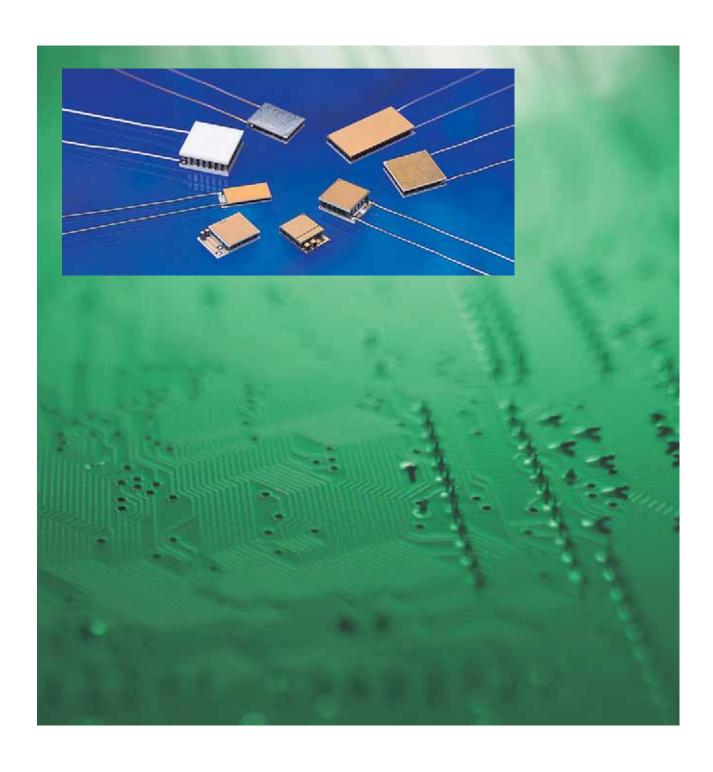


THERMO-MODULE



KELK LTD.

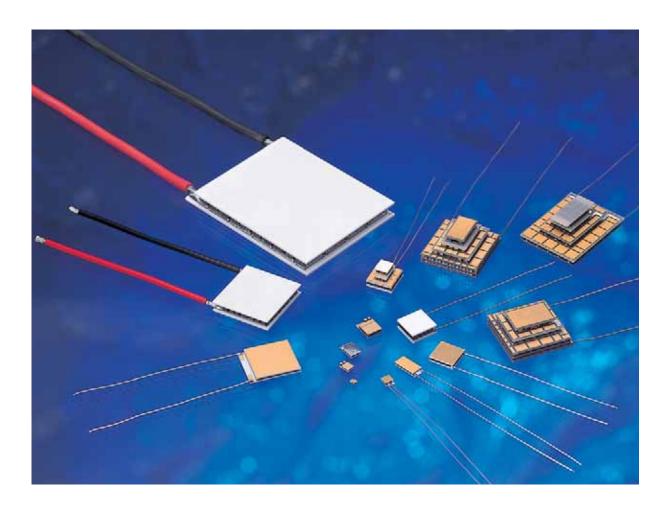
KELK THERMO-MODULE

The thermo-module is used in a wide range of applications where such merits as small, lightweight solid state device with no moving parts and as superiority in temperature controlling are much appreciated. Meanwhile it is a well-known fact that the thermo-module, especially in cooling mode, has lower energy efficiency compared to the compressor refrigerator having similar functions as the former. However, it is a fact too, that there are a lot of products to which the thermo-module is indispensable. We are confident that the thermo-module is promised to be applied for more and more products in future.

Since 1960 our company has been producing the Thermo-modules with melt-grown bismuth telluride semiconductor, and has been improving the performance and reliability of them along with, focusing mainly on the semiconductor process, developing many applied equipment and systems in which precise temperature control had been an indispensable requirement.

Since 1988, we have been supplying micro-modules, with high strength, sintered thermoelements, to the fiber-optic telecommunication industry all over the world. Moreover, since 1997, we have been mass-producing the "Z-material", having world-best performance in production, made by an innovative hot-forging process.

Therefore, our company not only has an expertise related to element production and assembly of the discrete Thermo-module, but also has one obtained from actual applications in a wide range of products. We vow to answer our client's continuously intensifying needs by offering higher performance, more reliable and cost efficient thermo-modules created in a future-looking research and development.



Advantages of KELK Thermo-module

Abundant standard models and flexible response to special requirements

KELK provides a broad range of thermo-electric cooler products, in response to the varied requests of our customers. KELK offers various kinds of TECs, including multi-purpose TECs with mass-volume reliability, and multi-stage TECs with high Delta-T. We also offer micro-modules and MiniTECs with high performance & reliability, using element material with world-beating performance and Delta-T. When custom-designs are requested, we can propose the optimal design based on our extensive experience.

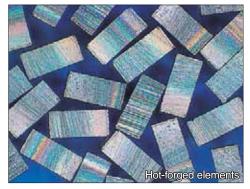
Advantage of Micro-module

Excellent & consistent performance with high reliability

All of KELK's micro-modules use hot-forged elements with the world's highest performance; our company developed these exclusively, and they are assembled using robotic automation. Compared with meltgrown elements, KELK's hot-forged elements are highly efficient, have very good mechanical strength, do not chip and have homogeneous consistency.

The high efficiency of our element material, together with our precision automated assembly process, results in micro-modules with high performance, consistent mass volume reliability, and excellent cost/performance. We have a wide range of

different product types, such as Enhanced series for high power, two-stage series for high Delta-T, and MiniTEC series for small footprint.









Note: All micro-modules are 100%-Screened by the Bellcore Standard plus 100% visually inspected under the microscope.

Advantage of multi-purpose module

- ·High reliability by 100% screening
- ·Hot-forged material is available for larger $\triangle \mathbf{T}$ or smaller power consumption

We use melt-grown element to assemble Multi-purpose module and conduct 100% screening (accept/reject inspection) by applying current, which promises high reliability. Meanwhile we newly developed special models having a long life for thermal cycling. For a larger ΔT or a smaller power consumption application, the high performance "Hot-forged material" is also available.



Multi-stage module assembled with hot-forged elements. Therefore, these modules have similar advantages as micro-module does. The latter uses AIN ceramics as the standard and has very low profile to improve resistance against shock and vibration.

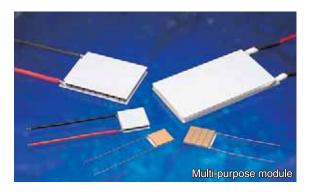




Table 1 Micro Modules

			Imax(A)	V max(volts)			△T max(°C)			Oc max(watts)		
Туре	Series	Model No.		Thj= 27 ℃	Thj= 50 ℃	Thj= 70 ℃	Thj= 27 ℃	Thj= 50 ℃	Thj= 70 ℃	Thj= 27 ℃	Thj= 50 ℃	Thj= 70 ℃
		KSML007	1.5	0.8	0.9	1.0	75	85	93	0.7	0.8	0.9
		KSML012	†	1.4	1.6	1.8	†	1	1	1.3	1.4	1.5
	ML	KSML018	1	2.2	2.4	2.7	†	1	1	1.9	2.1	2.2
		KSML023	†	2.8	3.1	3.4	1	†	1	2.4	2.6	2.9
		KSML029	†	3.5	3.9	4.3	†	†	1	3.0	3.3	3.6
		KSML031	1	3.7	4.2	4.6	1	1	1	3.2	3.5	3.8
		KSML035	1	4.2	4.7	5.2	1	1	1	3.7	4.0	4.3
		KSML047	1	5.7	6.4	7.0	†	1	1	4.9	5.4	5.8
_		KSMH007	2.0	0.7	0.9	1.0	75	85	93	0.9	1.1	1.2
dard		KSMH012	1	1.4	1.6	1.7	↑	†	1	1.7	1.9	2.0
tan		KSMH018	1	2.1	2.4	2.6	1	1	1	2.6	2.8	3.1
Single-stage Standard	МН	KSMH023	1	2.7	3.1	3.3	<u>†</u>	1	1	3.2	3.6	3.9
stai	IVIII	KSMH029	1	3.4	3.8	4.2	1	1	1	4.1	4.5	4.9
<u>a</u>		KSMH031	1	3.7	4.1	4.5	1	1	1	4.4	4.8	5.2
Sin		KSMH035	1	4.1	4.6	5.1	1	1	1	4.9	5.4	5.9
		KSMH047	1	5.5	6.2	6.8	1	1	1	6.6	7.3	7.9
	ЕН	KSEH007	2.4	8.0	0.9	1.0	75	85	93	1.2	1.3	1.4
		KSEH012	1	1.4	1.6	1.8	1	1	1	2.0	2.2	2.4
		KSEH018	1	2.1	2.4	2.6	<u> </u>	<u> </u>	<u>†</u>	3.0	3.3	3.6
		KSEH023	1	2.8	3.1	3.4	1	1	1	3.8	4.1	4.5
		KSEH029	1	3.5	3.9	4.3	1	1	1	4.8	5.2	5.7
		KSEH031	1	3.7	4.2	4.6	1	<u>†</u>	1	5.1	5.6	6.1
		KSEH035	1	4.2	4.7	5.2	1	1	1	5.8	6.3	6.8
		KSEH047	1	5.7	6.4	7.0	1	1	1	7.7	8.5	9.2
		K 2 M 0 0 6	2.6	0.9	1.0	1.1	97	109	120	0.8	0.9	1.0
		K 2 M 0 1 0	1	1.4	1.6	1.7	96	108	118	1.3	1.4	1.5
Two-stage		K 2 M 0 1 6	1	2.2	2.5	2.7	96	108	118	2.0	2.2	2.4
S-0,	EH	K 2 M 0 2 2	1	3.0	3.4	3.7	95	107	117	2.7	3.0	3.2
≥		K 2 M 0 2 8	Ť	3.8	4.3	4.7	95	107	117	3.4	3.7	4.0
		K 2 M 0 3 0	Ť	4.1	4.6	5.1	95	107	117	3.5	3.9	4.2
		K 2 M 0 3 4	Ī	4.6	5.2	5.7	94	106	116	4.1	4.5	4.9
		KSAL008	1.5	0.9	1.0	1.1	72.5	82	90	0.9	1.0	1.1
	AL	KSAL012	1	1.4	1.5	1.7	1	1	<u>†</u>	1.3	1.4	1.6
S		KSAL018	Î	2.1	2.3	2.5	Ť	1	Î	2.0	2.2	2.3
MiniTECs		KSAL023	1	2.6	2.9	3.2	1	1	1	2.5	2.7	3.0
Z.		KSAH008	2.0	0.9	1.1	1.2	71	80.5	88.5	1.1	1.2	1.3
	АН	KSAH012	1	1.4	1.6	1.7	1	<u>†</u>	1	1.7	1.8	2.0
	All	KSAH018	1	2.1	2.4	2.6	1	<u>†</u>	1	2.5	2.8	3.0
		KSAH023	1	2.7	3.1	3.4	1	1	<u> </u>	3.2	3.5	3.8

 \blacksquare All modules are screened by the following processes with the ACR change criterion of $\pm 2\%$.

Thermal Shock : -40/85°C Temperature Cycling

- \blacksquare Two-stage type modules are designed for relatively higher ΔT application.
- Footprint of MiniTECs is 50-75% smaller than that of standard TECs.
- Explanation of Imax,Vmax, ∆Tmax and Qmax are described in page 10.
- ■Dimensions of these products are "original" specification created by Komatsu Electronics Inc..



	Top ceramics		Bottom ceramics		Height	Height Height			
Model No.	W (mm)	L (mm)	W (mm)	L (mm)	H (mm)	tolerance (±mm)		Other Specifications	
KSML007	4.4	4.4	4.4	4.4	2.02	0.1	0		
KSML012	4.3	6.5	4.3	7.6	2.02	1	0	1) Ceramics	
KSML018	6.0	6.2	6.0	7.2	2.02	1	0	All models can be	
KSML023	6.0	8.2	6.0	8.2	2.02	†	0	assembled with alumina	
KSML029	6.0	10.2	6.0	10.2	2.02	†	0	&/or aluminum nitride	
KSML031	8.0	8.0	8.0	8.0	2.02	†	0	ceramics. (AL/AH series	
KSML035	6.0	12.2	6.0	12.2	2.02	1	0	is excluded)	
KSML047	8.0	12.2	8.0	12.2	2.02	1	0		
KSMH007	4.4	4.4	4.4	4.4	1.65	0.1	0	2) Metallization	
KSMH012	4.3	6.5	4.3	7.6	1.65	†	0	Standard metallization is	
KSMH018	6.0	6.2	6.0	7.2	1.65	†	0	CuNiAu with Au thickness	
KSMH023	6.0	8.2	6.0	8.2	1.65	1	0	of 0.25 μ m	
KSMH029	6.0	10.2	6.0	10.2	1.65	1	0		
KSMH031	8.0	8.0	8.0	8.0	1.65	1	0	3) Assembly solder	
KSMH035	6.0	12.2	6.0	12.2	1.65	1	0	SnSb(232°C) or AuSn(280	
KSMH047	8.0	12.2	8.0	12.2	1.65	1	0	$^{\circ}\!C)$ is available for	
KSEH007	4.4	4.4	4.4	4.4	1.65	0.1	0	assembly solder.	
KSEH012	4.3	6.5	4.3	7.6	1.65	1	0	However, the assembly	
KSEH018	6.0	6.2	6.0	7.2	1.65	1	0	solder of the model	
KSEH023	6.0	8.2	6.0	8.2	1.65	1	0	KSML047/KSMH047/KSE	
KSEH029	6.0	10.2	6.0	10.2	1.65	1	0	H047 Two-stage are SnSb	
KSEH031	8.0	8.0	8.0	8.0	1.65	1	0	solder.	
KSEH035	6.0	12.2	6.0	12.2	1.65	1	0		
KSEH047	8.0	12.2	8.0	12.2	1.65	1	0	4) InSn(117°C),BiSn(138	
K2M006	4.05	4.05	4.05	4.05	3.0	0.2	0	°C) SnAgCu(217°C)	
K 2 M 0 1 0	4.05	6.05	4.05	6.05	3.0	1	0	or SnSb(232℃) are	
K 2 M 0 1 6	6.05	6.25	6.05	6.25	3.0	1	0	available for pretinning	
K 2 M 0 2 2	6.05	8.25	6.05	8.25	3.0	<u>†</u>	0	solder.	
K 2 M 0 2 8	6.05	10.25	6.05	10.25	3.0	Ť	0	Other solders specified by	
K 2 M 0 3 0	8.05	8.05	8.05	8.05	3.0	T	0	customers are also	
K 2 M 0 3 4	6.05	12.05	6.05	12.05	3.0	1	0	available. (Solder volume	
KSAL008	2.56	2.56	2.56	3.56	1.1	0.1	0	control is available.)	
KSAL012	2.56	3.8	2.56	4.8	1.1	Ť	0		
KSAL018	3.8	3.8	3.8	4.8	1.1	Ť	0	5) ΔTmax is measured in	
KSAL023	3.8	5.04	3.8	6.04	1.1	Ī	0	vacuum of 0.13Pa	
KSAH008	2.56	2.56	2.56	3.56	0.97	0.1	0	(Δ Tmax in air or nitrogen	
KSAH012	2.56	3.8	2.56	4.8	0.97	Î	0	is 5 to 6 °C lower than that	
KSAH018	3.8	3.8	3.8	4.8	0.97	Ť	0	in vacuum.)	
KSAH023	3.8	5.04	3.8	6.04	0.97	Ī			

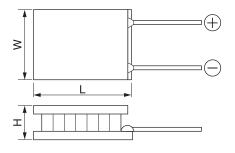


Table 2 Multi-purpose & Multi-stage Modules

	Model No.	Imax(A)	V max(volts)			△T max(°C)			Qc max (watts)		
Туре			Thj= 27 ℃	Thj= 50 ℃	Thj= 70 ℃	Thj= 27 ℃	Thj= 50 ℃	Thj= 70 ℃	Thj= 27 ℃	Thj= 50 ℃	Thj= 70 ℃
	KSM-04007C	4.0	0.8	0.9	1.0	64	73	81	2.0	2.2	2.5
		4.0				04	13	01			
	KSM-04017C	1	2.0	2.2	2.5		-	I	4.8	5.4	6.0
	KSM-04031C	1	3.6	4.1	4.5	1	1	<u>†</u>	8.7	9.9	10.9
o o	KSM-04071C	1	8.3	9.2	10.2	1	<u>†</u>	<u>†</u>	19.9	22.6	24.9
킇	KSM-04127C	Ť	14.8	16.7	18.3	1	1	Ī	35.6	40.4	44.5
E C	KSM-06007C	6.0	8.0	0.9	1.0	1	1	1	3.0	3.4	3.7
ose	KSM-06017C	1	2.0	2.2	2.4	1	1	†	7.2	8.2	9.0
g d	KSM-06031C	1	3.6	4.1	4.5	†	†	†	13.1	14.9	16.4
ig.	KSM-06071C	†	8.3	9.2	10.2	†	†	†	30.0	34.1	37.6
Multi-purpose module	KSM-06127C	1	14.7	16.5	18.2	†	1	†	53.8	61.0	67.2
	KSM-09007C	9.0	8.0	0.9	1.0	1	1	1	4.5	5.1	5.6
	KSM-09017C	1	2.0	2.2	2.4	1	1	1	10.8	12.3	13.5
	KSM-09031C	1	3.6	4.0	4.4	1	1	1	19.7	22.4	24.6
	KSM-09071C	1	8.3	9.2	10.2	†	1	1	45.2	51.2	56.4
	K2M-01004	1.6	1.3	1.5	1.7	101.0	114.0	125.0	0.6	0.7	0.7
	K2M-01011	1.6	3.8	4.3	4.7	101.0	114.0	125.0	1.7	1.8	2.0
n <u>e</u>	K3M-01002	1.7	2.1	2.3	2.6	124.0	140.0	153.0	0.4	0.5	0.5
pou	K3M-01004	1.5	3.8	4.2	4.7	120.0	136.0	149.0	0.7	0.8	0.8
ge n	K4MA010	4.6	14.9	16.7	18.3	124.0	140.0	154.0	6.3	7.0	7.6
sta	K4MB005	5.3	16.1	18.0	19.8	131.0	148.0	162.0	4.0	4.3	4.6
Multi-stage module	K5MA004	4.6	15.0	16.8	18.4	136.0	153.0	168.0	2.9	3.2	3.4
Ē	K5MB002	5.2	16.0	18.0	19.7	143.0	161.0	176.0	1.7	1.8	2.0
	K3MC004	5.0	7.4	8.3	9.1	111.0	126.0	139.0	6.5	7.2	7.8
	K4MC005	4.6	14.9	8.0	8.7	124.0	140.0	154.0	3.2	3.5	3.8

■ Multi-purpose module:

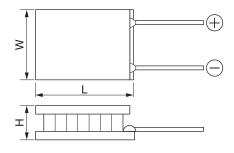
- 1. $\triangle Tmax$ is described as the value in air.
- 2. 100% screened.
- 3. Pb-free, fatigue-resistant SnAgCu(melting point:217°C) is used as the assembly solder.
- 4. \pm 0.025mm height allowance is available by lapping.

■ Multi-stage module:

- 1. High performance hot-forged element is used.
- 2. SnSb (melting point:232°C) or SnAgCu (melting point:217°C) is used as the assembly solder.
- 3. △Tmax is described as the value in vacuum of 0.13Pa..
- 4. InSn is available for pretinning solder. Pretinning is only on hot side.
- Explanation of Imax,Vmax, △Tmax and Qmax are described in page 10.



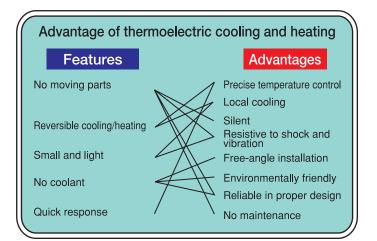
	Top ceramics		Bottom ceramics		Height	Height	Ceramic	Metallization		Pb-free
Model No.	W (mm)	L (mm)	W (mm)	L (mm)	H (mm)	tolerance (±mm)	material	Nil	Cu-Ni-Au (Pretinning)	
KSM-04007C	10.3	10.3	10.3	12.2	4.65	0.15		0		0
KSM-04017C	15.0	15.0	15.0	17.0	4.65	†		0		0
KSM-04031C	20.0	20.0	20.0	22.0	4.65	1	Alumina	\bigcirc		\circ
KSM-04071C	30.0	30.0	30.0	31.5	4.65	1		\bigcirc		0
KSM-04127C	40.0	40.0	40.0	41.5	4.65	†		\bigcirc		\circ
KSM-06007C	10.3	10.3	10.3	12.2	3.8	1		0		0
KSM-06017C	15.0	15.0	15.0	17.0	3.8	1		0		0
KSM-06031C	20.0	20.0	20.0	22.0	3.8	1	Alumina	\bigcirc		\bigcirc
KSM-06071C	30.0	30.0	30.0	31.5	3.8	†		\bigcirc		\bigcirc
KSM-06127C	40.0	40.0	40.0	41.5	3.8	1		\circ		\bigcirc
KSM-09007C	15.0	15.0	15.0	15.0	5.5	1		0		0
KSM-09017C	22.0	22.0	22.0	22.0	5.5	1	Alumina			\circ
KSM-09031C	30.0	30.0	30.0	30.0	5.5	†	Alumna	\bigcirc		0
KSM-09071C	44.0	44.0	44.0	44.0	5.5	†		\bigcirc		\circ
K2M-01004	4.4	4.4	4.4	6.6	4.5	0.2		0		0
K2M-01011	4.4	6.6	8.7	8.7	4.5	0.2	Alumina	\bigcirc		\circ
K3M-01002	3.0	3.0	6.0	6.0	4.3	0.3	/ (larriiria			\circ
K3M-01004	4.4	4.4	8.7	8.7	6.5	0.3		\circ		0
K 4 M A 0 1 0	8.5	13.0	19.25	20.75	8.2	0.5	A luma in una		0	0
K4MB005	6.6	11.0	19.25	20.75	8.2	0.5	Aluminum nitride		0	0
K5MA004	6.6	11.0	19.25	20.75	10.3	0.5	(AIN)		0	0
K5MB002	5.3	5.3	19.25	20.75	10.3	0.5	(7.111)		0	0
K3MC004	8.5	13.0	21.5	28.0	7.3	0.4	Aluminum nitride			\circ
K4MC005	6.6	11.0	21.5	28.0	9.4	0.5	(AIN)			\circ



Application of Thermo-module

The inherent advantages of thermo-module are : a small, solid -state device, can easily do precise cool/heat control only by applying current, has a relatively wide operating temperature of -100 to 100° C, and is very reliable when properly used.

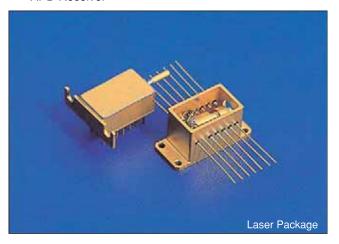
There could be extensive applications to utilize these advantages, and thermo-module is actually used in very wide range of equipment and devices. Typical examples can be found in semiconductor process equipment inevitably requiring precise temperature control, and wavelength control of laser diodes for fiber-optic telecommunication.



Application Examples

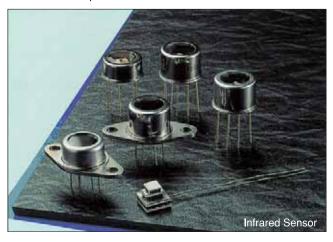
Fiber-optic Telecommunication

- ·Transmiter Laser
- ·EDFA Pump Laser
- ·APD Receiver



Sensors

- Infared Detector
- ·High Sensitivity CCD
- ·Photo Multiplier



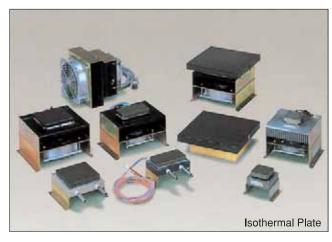
Semiconductor Process

- ·Cooling Plate ·Circulator
- ·Chemical Circulator
- Precision Air Conditioning Unit



Miscellaneous

- ·Isothermal Bath
- ·Isothermal Plate
- Dehumidifier
- ·Gene Amplifier
- ·Cooler Box



Principle of Thermoelectric Cooling/Heating and Structure of Thermo-module

Principle of Cooling/Heating

The thermo-module is a sort of heatpump made by thermo-electric semiconductor. The physical phenomenon used here, as a principle, is shown in right Fig. 1. Two kind of thermoelectric semiconductors, which are made of the 'P-type' and 'N-type' element, are electrically connected with a metallic strip to form a π -type series circuit called 'P-N couple'. When a current is applied to N \rightarrow P direction heat absorption occurs at the top of π , and heat generates at the bottom. Thus, as the result of the Peltier effect, heat is pumped from the top to the bottom.

The above phenomenon is better explained as follows. At the top of the π , where electrons move P \rightarrow N direction, the current conversely runs N \rightarrow P, electrons transfer in their energy state to a higher level absorbing the vibration energy from the surrounding crystal lattice lowering temperature of the top. Meanwhile, at the bottom of the π , where electrons go N \rightarrow P direction and the current flows vice verse, electrons having absorbed lattice vibration energy at the cold side transfer their low energy state to a higher one. In this process, the electron gives their excess energy to the surrounding lattice increasing the vibration energy, which results in a temperature rise.

Heat absorption by the Peltier effect increases in proportion to the applied current however the Joule heat originated from the internal electrical resistance soars in proportion to a square of the current. As the result, there exists maximum absorption point of heat at a corresponding current. Excess current harms heat absorption on the contrary.

Single-stage module and its structure

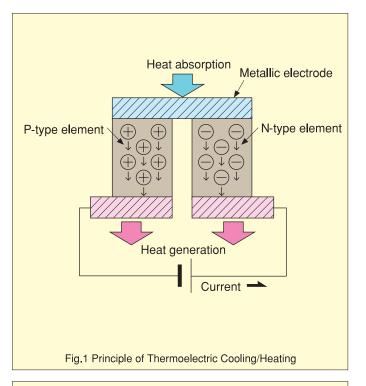
A single-stage module is made by sandwiching the element couples between the two ceramic plates with the electrode metal to make a series circuit(Fig.2). The number of the element couples in a module ranges from several to over one hundred. In proportion to the number of couples, the heat absorption(or heat generation) of the module increases. The hot side of the module requires a heat-sink for radiating heat: the total quantity of heat load at the cold side plus the power consumption. For a heat-sink, air-cooled fins or water-cooled plates are used. Ceramic pads at both sides must make thermally well conducting interfaces with head-load and heat-sink.

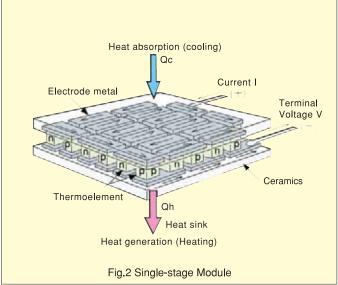
Multi-stage module and its structure

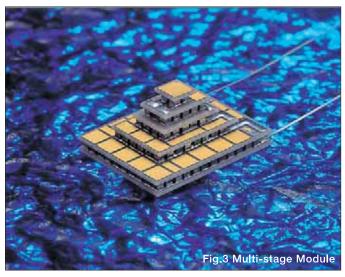
When the cold side temperature is 27°C, the maximum temperature difference between the cold and the hot side of a single-stage module is about 68°C. However, in a multistage module, a large temperature difference can be obtained. The 5-stage module in Fig.3 can give a maximum temperature difference of 123°C.(All in vacuum)

The multi-stage module can achieve a big temperature difference by a pyramid shape configuration. Because it is necessary for a lower stage to absorb the heat influx from an upper stage while obtaining positive temperature difference between the two stages.

When the temperature difference is very large the heat absorption capacity significantly decreases. Therefore vacuum container is commonly used to avoid thermal convection and conduction of the atmosphere. When the cold side temperature go down to around -100° C, radiation effect from the surroundings become large enough for the cold side to have to have a shield. Six-stage is a usual maximum number of stages because, below -100° C, the performance of the thermo-element significantly degrades.







How to Select and Use Thermo-module

Performance Parameters and Performance Diagram

In Table 1 (page 4) the following parameters are shown to describe performance characteristics of thermo-modules.

Imax : Maximum current ----- Current at ΔTmax, Qc=0

Vmax: Maximum terminal voltage ------ Terminal voltage at Imax, ΔTmax and Qc=0

ΔTmax : Maximum temperature difference ---- Temperature difference between the cold side and the

hot side at junctions of element and electrode. at Imax, Qc=0

Qcmax : Maximum heat pumped at the cold side --- Heat pumped at Imax, ΔT=0

Thj: Hot junction temperature ----- Temperature at element/electrode junction at the hot side

The performance of the module varies due to temperature dependence of thermodynamic behavior and of performance of thermoelement. From this reason performance as Qc and ΔT improve with raising Thj temperature from 27°C to 70°C. Fig. 4 is a normalized performance diagram of a single-stage module, in which relationships of Qc-V- ΔT are normalized by each maximum value using the current as the parameter. When Qcmax, ΔT max, Vmax and Imax in Table 1 are given, performance diagrams of respective models can be obtained. Fig. 5 shows KSM-06127A(Thi=50°C).

Selection of Appropriate Module

Usually, it is necessary to prevent current value I from exceeding 70% of Imax. Therefore, a module should be selected to satisfy the condition in Fig.4 in which the heat load Qc does not exceed the Qc/Qcmax decided by I/Imax=0.7 and $\triangle T/\triangle T$ max. The Qcmax to satisfy this condition can be found by using I/Imax=0.7(red line in Fig. 4).

$$Qcmax > \frac{0.94 \triangle Tmax \cdot Qc}{0.91 (0.94 \triangle Tmax - \triangle T)}$$

Table2(page6) shows $\triangle Tmax=73^{\circ}C$ at Thj=50 $^{\circ}C$, and giving Qc=12W, $\triangle T=53^{\circ}C$

Qcmax >
$$\frac{0.94 \times 73 \times 12}{0.91 (0.94 \times 73 - 53)} = 57.9 (W)$$

You can choose KSM-06127A with Qc max of 61W from Table 2(page6). (note: Plural modules can be used from design restrictions.)

Determination of Operating Parameters

In order to determine the current and voltage in operation, you can use Fig. 5.

And from the current and voltage you get the power consumption and heat generation at the hot side. The procedure is as follows.

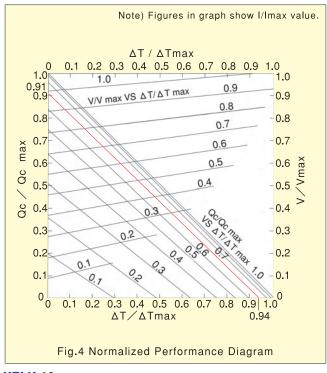
Step1 : Current(I) ---- From intersection (a) of Qc=12 and Δ T=53 $^{\circ}$ C you can find necessary I=4.2A.

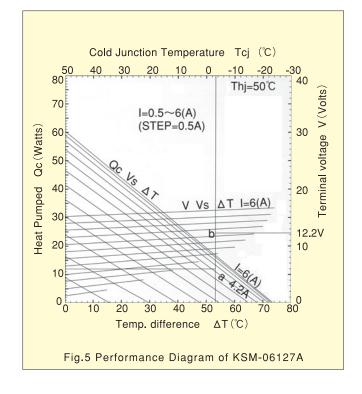
Step2 : Voltage(V) ---- From intersection (b) of Δ T=53°C and the V vs ΔT line of 4.2A, you can obtain necessary voltage of V=12.2V to operate.

Step3: Hot side Heat Generation(Qh):

Qh corresponds to a sum of Qc and power consumption in a module. Therefore, heat generation Qh=Qc+P=12+4.2×12.2=63(W)

Please note that it is necessary to dissipate this heat by adopting an appropriate heatsink in order to maintain the hot side temperature(Thj) at 50°C.



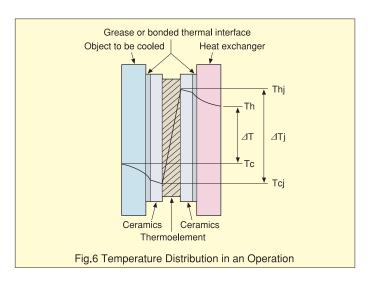


Terminal Resistance and Temperature Distribution

When an object is cooled by a thermo-module, temperature distribution will be shown as in Fig. 6. At the cold side, between the cooled object and the cold junction, there are such thermal resistances as greased or bonded interface plus ceramics. Therefore, the cold junction temperature should be set at lower than that of the cooled object.

At the hot side, there are similar thermal resistances between the heatsink and the hot junction, so the hot junction temperature is higher than the heatsink. If a comparison is made between junction and such heat dissipating media as air or water, the temperature difference would be much larger. Depending on the area and cooling method (natural air, forced air, water) of the heatsink, thermal resistance greatly varies. Furthermore, thermal resistance also greatly depends on flow rate of the media.

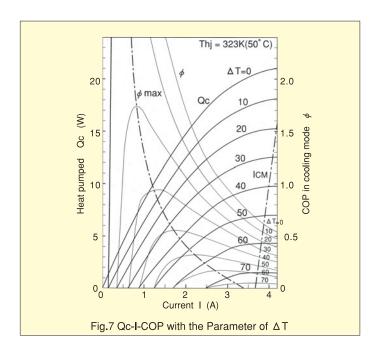
For further information, please contact our technical department.



■Coefficient of Performance(COP)

The COP of the thermo-module significantly changes by temperature difference ΔT and by input current I. Fig. 7 shows an example of 71 couple module having Imax of 4A.(The cooling-mode COP is written as $\phi = Qc/IV$.)

The figure indicates that the larger temperature difference you wish to obtain, the smaller COP you will get, resulting in less efficiency of the system. At a specific ΔT , there is an optimum current which maximizes the COP indicated by ϕ max line, however 50 to 70% of Imax is commonly adopted for total economy.



Caution in Use

- Never fail to confirm the polarity. In the standard arrangement, the right lead is the plus when you look down a module from the opposite face to the lead side face.
- DC current should be used and ripple content of 10 % or less is recommended.
- Be sure to attach a heatsink to the hot side when you input current. The solder would melt with no heatsink. The pressure contact with grease is properly done by 0.2~0.5Mpa. Use heat isolation technique when you use metal screws to attach a heatsink.
- Continuous-use temperature should be 80°C or less and do not exceed 160°C even in a short time.
- Avoid a mechanical shock in handling a module. Do not machine a module.
- A module should be sealed with epoxy or something when used in an atmosphere below dew point.
- When you anticipate a thermal cycling, please consult our technical department.



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(The name of the company was changed from Komatsu electronics Inc. to KELK Ltd. on July 1.2008)

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